



#### 0.2A SURFACE MOUNT SCHOTTKY BARRIER DIODE

### Product Summary (@TA = +25°C)

| V <sub>RRM</sub> (V) | I <sub>O</sub> (mA) | V <sub>FMAX</sub> (V)<br>@100mA | I <sub>RMAX</sub> (μ <b>A</b> ) |
|----------------------|---------------------|---------------------------------|---------------------------------|
| 30                   | 200                 | 0.70                            | 0.4                             |

## **Description**

The SDM02M30CLP3 is a Schottky barrier diode optimized for low forward voltage drop and very-low reverse leakage current in a common cathode DFN package. Encapsulated in the small DFN1006 with footprint of 0.6mm<sup>2</sup> and ultra-low package profile, this device is designed for saving PCB space in portable electronic devices.

### **Applications**

- Portable Device
- Mobile Applications
- LCD and Keypad Backlighting
- Clamping Protection
- Reverse Voltage and Current Protection
- Freewheeling Diode

## **Features and Benefits**

- Small Leadless Surface Mount Package (1.0mm × 0.6mm × 0.37mm)
- Very Low Reverse Leakage Current
- Low Forward Voltage
- Fast Reverse Recovery
- Low Capacitance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

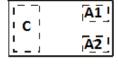
### **Mechanical Data**

- Case: X2-DFN1006-3
- Case Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: Cathode Bar
- Terminals: Finish—NiPdAu Annealed over Copper Leadframe.
  Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.001 grams (Approximate)

X2-DFN1006-3



**Bottom View** 



Top View C: Cathode A1&A2: Anode 1&2



**Equivalent Circuit** 

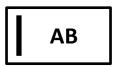
### Ordering Information (Note 4)

| Part Number     | Case         | Packaging          |
|-----------------|--------------|--------------------|
| SDM02M30CLP3-7B | X2-DFN1006-3 | 10,000/Tape & Reel |

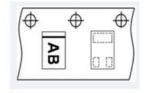
Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



AB = Product Type Marking Code AB = LC or LC Bar Denotes Cathode Side





# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic   | Symbol   | Value | Unit |
|--|--|-------|------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage | V <sub>RRM</sub><br>V <sub>RWM</sub><br>V <sub>R</sub> | 30    | ٧    |
| Average Rectified Output Current (Total)   | lo   | 200   | mA   |
| Non-Repetitive Peak Forward Surge Current (8.33ms Half-Sine Waveform, per Diode)       | I <sub>FSM</sub>                                       | 2     | А    |

# **Thermal Characteristics**

| Characteristic  | Symbol                            | Value       | Unit |
|---|-----------------------------------|-------------|------|
| Power Dissipation(Note 5) (Total)                           | Pd                                | 350         | mW   |
| Typical Thermal Resistance Junction to Ambient Air (Note 5) | R <sub>OJA</sub>                  | 350         | °C/W |
| Operating and Storage Temperature Range                     | T <sub>J</sub> , T <sub>STG</sub> | -55 to +150 | °C   |

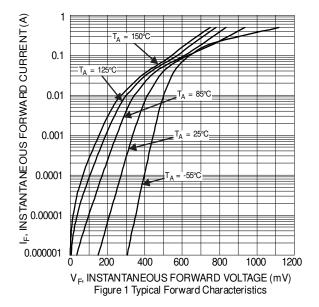
# **Electrical Characteristics** (@ $T_A = +25^{\circ}C$ , per diode unless otherwise specified.)

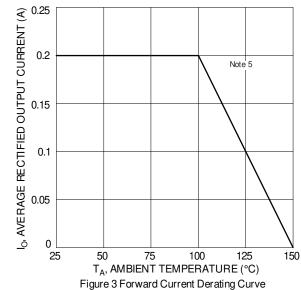
| Characteristic           | Symbol          | Min | Тур                          | Max                          | Unit  | Test Condition   |
|--------------------------|-----------------|-----|------------------------------|------------------------------|-------|--|
| Forward Voltage          | V <sub>F</sub>  |     | 0.28<br>0.34<br>0.42<br>0.63 | 0.34<br>0.40<br>0.48<br>0.70 | ٧     | I <sub>F</sub> = 0.1mA<br>I <sub>F</sub> = 1mA<br>I <sub>F</sub> = 10mA<br>I <sub>F</sub> = 100mA, |
| Leakage Current (Note 6) | I <sub>R</sub>  | _   | 0.014<br>0.040               | 0.15<br>0.40                 | μΑ    | V <sub>R</sub> = 10V<br>V <sub>R</sub> = 30V   |
| Reverse Recovery Time    | t <sub>RR</sub> |     | 2                            |                              | ns ns | $I_F = 10$ mA, $I_R = 10$ mA, $I_{RR} = 1$ mA  |
| Total Capacitance        | Ст              |     | 3.3                          |                              | pF    | $V_R = 5.0V_{DC}$ , $f = 1MHz$   |

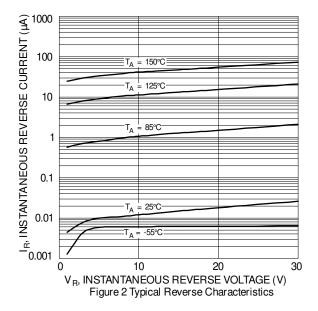
Notes:

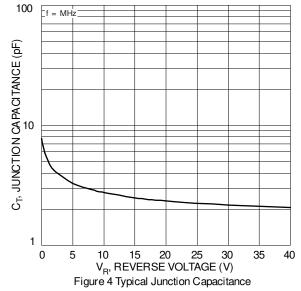
<sup>5.</sup> Part mounted on FR-4 PCB with recommended pad layout, which can be found on our website at http://www.diodes.com/package-outlines.html. 6. Short duration pulse test used to minimize self-heating effect.









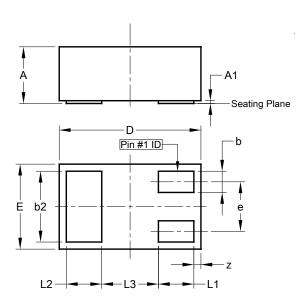




# **Package Outline Dimensions**

 $Please \ see \ http://www.diodes.com/package-outlines.html \ for \ the \ latest \ version.$ 

#### X2-DFN1006-3

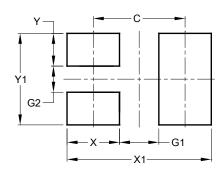


| X2-DFN1006-3         |      |      |      |  |
|----------------------|------|------|------|--|
| Dim                  | Min  | Max  | Тур  |  |
| Α                    |      | 0.40 |      |  |
| <b>A</b> 1           | 0.00 | 0.05 | 0.03 |  |
| b                    | 0.10 | 0.20 | 0.15 |  |
| b2                   | 0.45 | 0.55 | 0.50 |  |
| D                    | 0.95 | 1.05 | 1.00 |  |
| Е                    | 0.55 | 0.65 | 0.60 |  |
| е                    | -    | -    | 0.35 |  |
| L1                   | 0.20 | 0.30 | 0.25 |  |
| L2                   | 0.20 | 0.30 | 0.25 |  |
| L3                   | -    | -    | 0.40 |  |
| Z                    | 0.02 | 0.08 | 0.05 |  |
| All Dimensions in mm |      |      |      |  |

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### X2-DFN1006-3



| Dimensions | Value (in mm) |
|------------|---------------|
| С          | 0.70          |
| G1         | 0.30          |
| G2         | 0.20          |
| Х          | 0.40          |
| X1         | 1.10          |
| Υ          | 0.25          |
| Y1         | 0.70          |



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